WESTCODE

An IXYS Company

Date:- 26th Nov 2007

Data Sheet Issue:- 1

Prospective Data

Rectifier Diode

Types W104CF#200 to W104CF#220

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	2000-2200	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	2100-2300	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, T_{sink}=55°C, (note 2)	10434	A
$I_{F(AV)M}$	Maximum average forward current. T_{sink}=100°C, (note 2)	7721	A
$I_{F(AV)M}$	Maximum average forward current. T_{sink}=100°C, (note 3)	4810	A
$I_{F(RMS)}$	Nominal RMS forward current, T_{sink}=25°C, (note 2)	18824	A
$I_{F(d.c.)}$	D.C. forward current, T_{sink}=25°C, (note 4)	16589	A
I_{FSM}	Peak non-repetitive surge t_p=10ms, V_{rm}=60%V_{RRM}, (note 5)	83.7	kA
I_{FSM2}	Peak non-repetitive surge t_p=10ms, V_{rm}≤10V, (note 5)	92.0	kA
I^2t	I^2t capacity for fusing t_p=10ms, V_{rm}=60%V_{RRM}, (note 5)	35.0×10^6	A^2s
I^2t	I^2t capacity for fusing t_p=10ms, V_{rm}≤10V, (note 5)	42.3×10^6	A^2s
$T_{j\,op}$	Operating temperature range	-40 to +175	°C
T_{stg}	Storage temperature range	-55 to +175	°C

Notes:-
1) De-rating factor of 0.13% per °C is applicable for T_j below 25°C.
2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
3) Single side cooled, single phase; 50Hz, 180° half-sinewave.
4) Double side cooled.
5) Half-sinewave, 175°C T_j initial.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V_{FM}	Maximum peak forward voltage	-	-	0.9	I_{FM}=4500A	V
V_{FM}	Maximum peak forward voltage	-	-	1.04	I_{FM}=8000A	V
V_{T0}	Threshold voltage	-	-	0.711		V
r_T	Slope resistance	-	-	0.041		mΩ
I_{RRM}	Peak reverse current	-	-	20	Rated V_{RRM}, T_j=25°C	mA
		-	-	200	Rated V_{RRM}	
R_{thJK}	Thermal resistance, junction to heatsink	-	-	0.0065	Double side cooled	K/W
		-	-	0.0130	Single side cooled	K/W
F	Mounting force	81	-	99	Note 2	kN
W_t	Weight	-	2.0	-	Outline option FD	kg
		-	2.8	-	Outline options FC	

Notes:-
1) Unless otherwise indicated T_j=175°C.
2) For other clamp forces, please consult factory.

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V_{RRM} V	V_{RSM} V	V_R DC V
20	2000	2100	1250
22	2200	2300	1350

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^{\,2} + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T}$$ and: $$W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j\max} - T_K$$

Where V_{T0}=0.711V, r_T=0.041mΩ

R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below

Supplementary Thermal Impedance				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave Double Side Cooled	0.00707	0.00689	0.00673	0.0065
Square wave Single Side Cooled	0.01359	0.01349	0.01323	0.0130
Sine wave Double Side Cooled	0.00697	0.00678	0.00654	
Sine wave Single Side Cooled	0.01348	0.01328	0.01303	

Form Factors				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave	2.449	1.732	1.414	1
Sine wave	2.778	1.879	1.57	

5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F, on page 6 is represented in two ways;
(i) the well established V_{T0} and r_T tangent used for rating purposes and
(ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

175°C Coefficients	
A	0.420349898
B	0.01827275
C	1.150657×10^{-5}
D	4.086984×10^{-3}

5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}}\right)$$

Where *p = 1* to *n, n* is the number of terms in the series and:
t = Duration of heating pulse in seconds.
r_t = Thermal resistance at time t.
r_p = Amplitude of p_{th} term.
τ_p = Time Constant of r_{th} term.

The coefficients for this device are shown in the tables below:

D.C. Double Side Cooled				
Term	1	2	3	4
r_p	3.424745×10^{-3}	1.745273×10^{-3}	8.532017×10^{-4}	3.457329×10^{-4}
τ_p	1.125391	0.1878348	0.02788979	8.430889×10^{-3}

D.C. Single Side Cooled				
Term	1	2	3	4
r_p	8.375269×10^{-3}	2.518437×10^{-3}	1.193758×10^{-3}	7.45432×10^{-4}
τ_p	8.929845	0.4711304	0.08221244	0.01221961

Curves

Figure 1 – Forward characteristics of Limit device

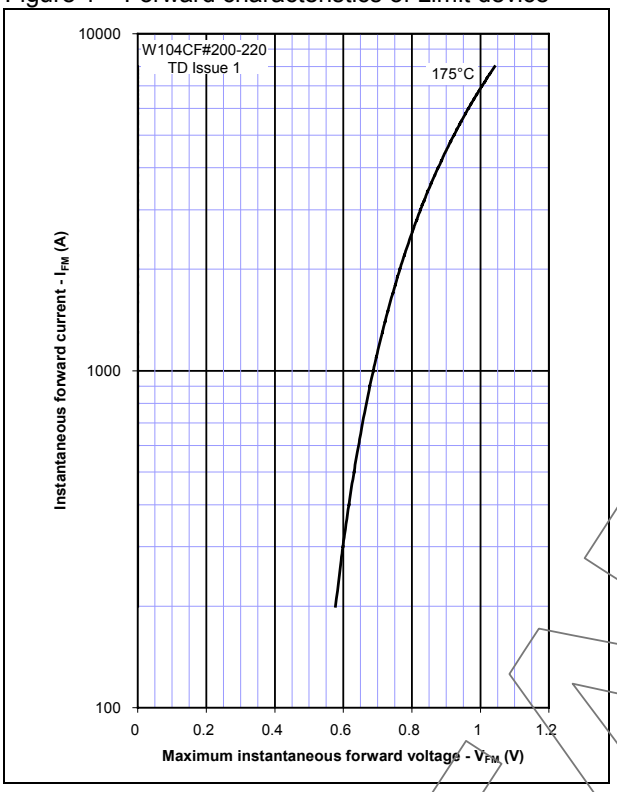


Figure 2 – Transient thermal impedance

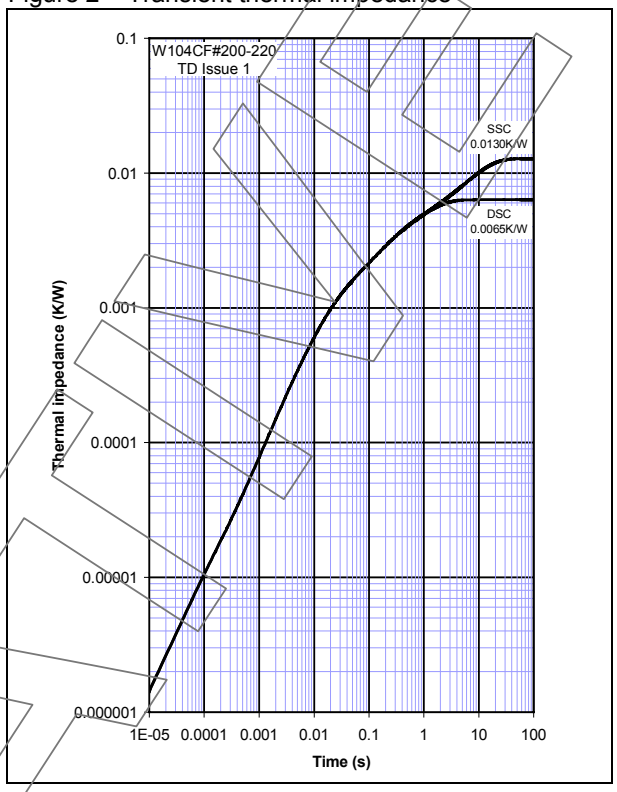


Figure 3 – Maximum Surge Rating

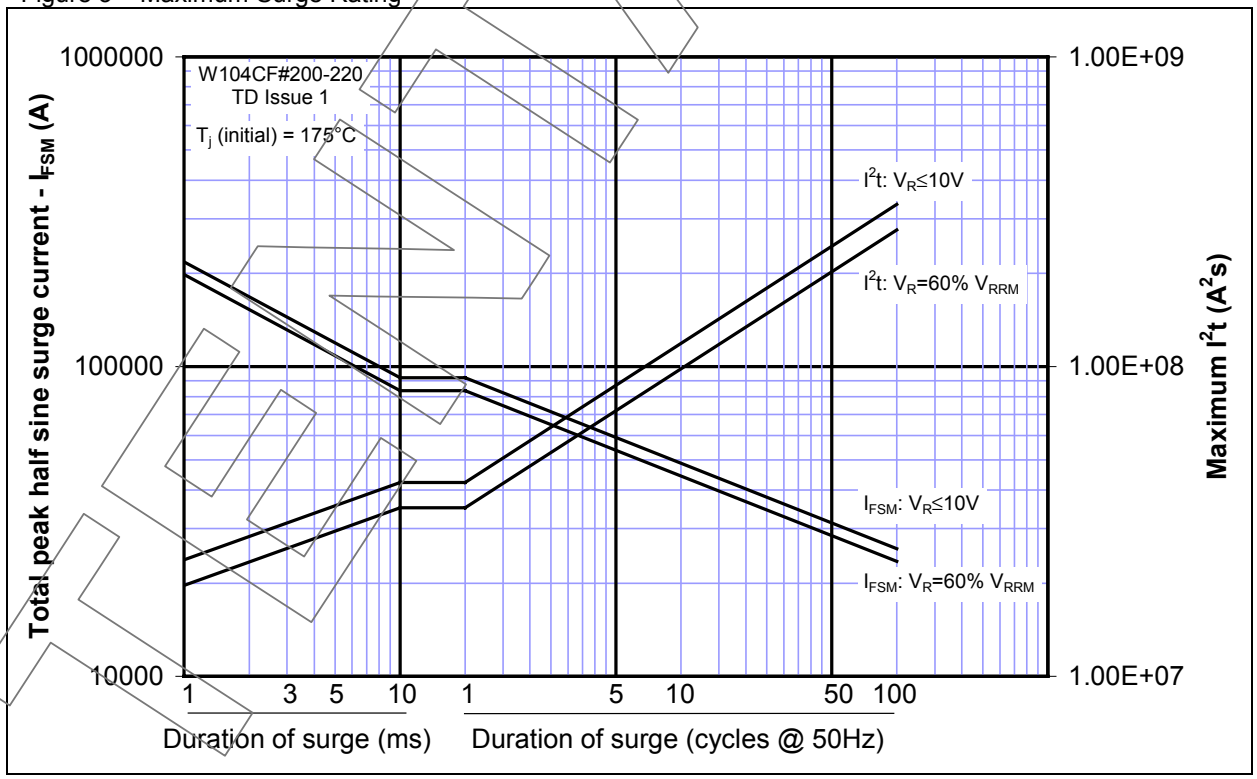


Figure 8 – Forward current vs. Power dissipation – Double Side Cooled

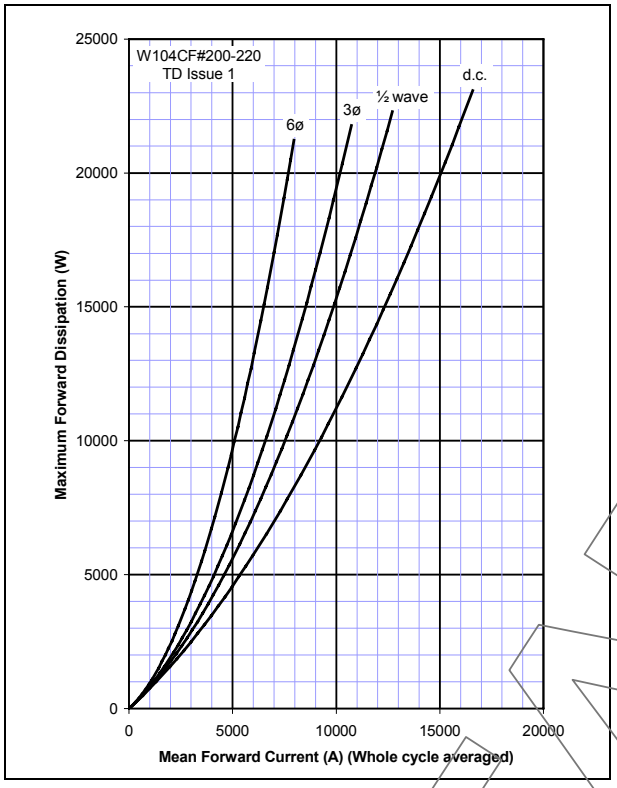


Figure 9 – Forward current vs. Heatsink temperature – Double Side Cooled

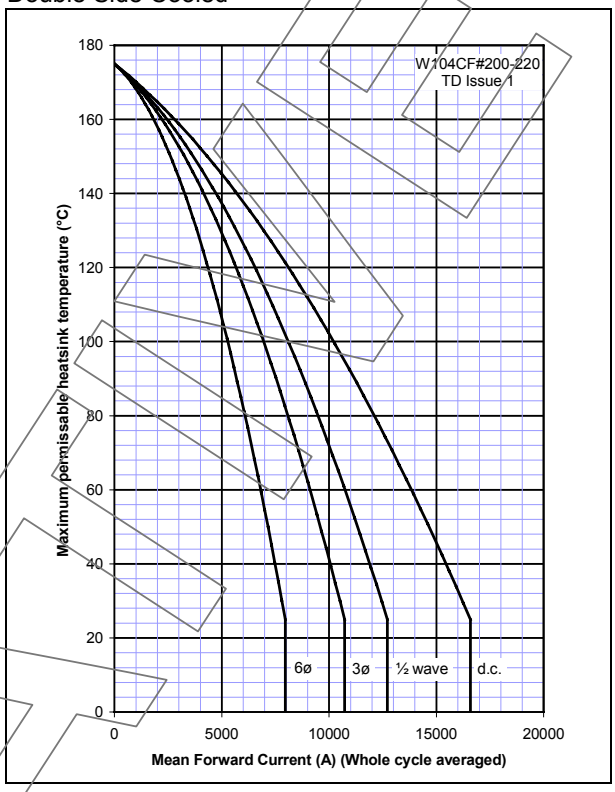


Figure 10 – Forward current vs. Power dissipation – Single Side Cooled

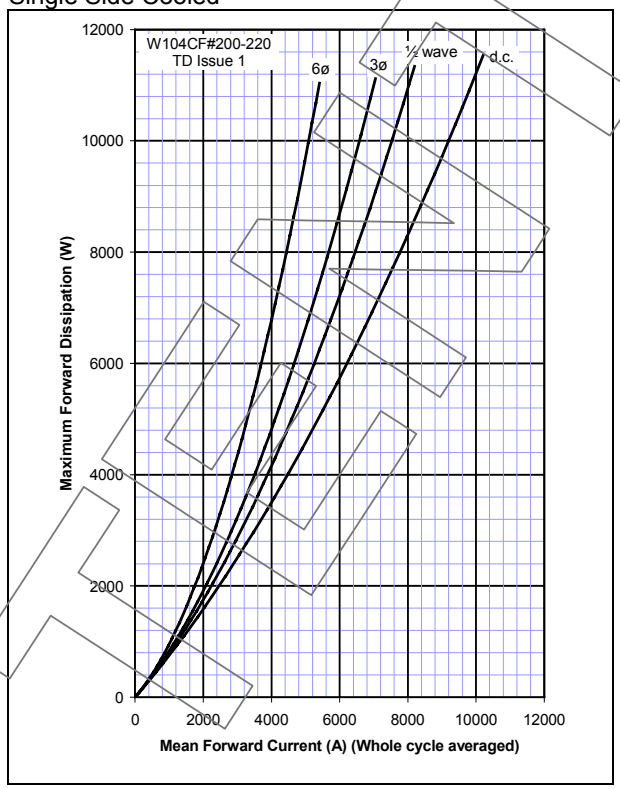
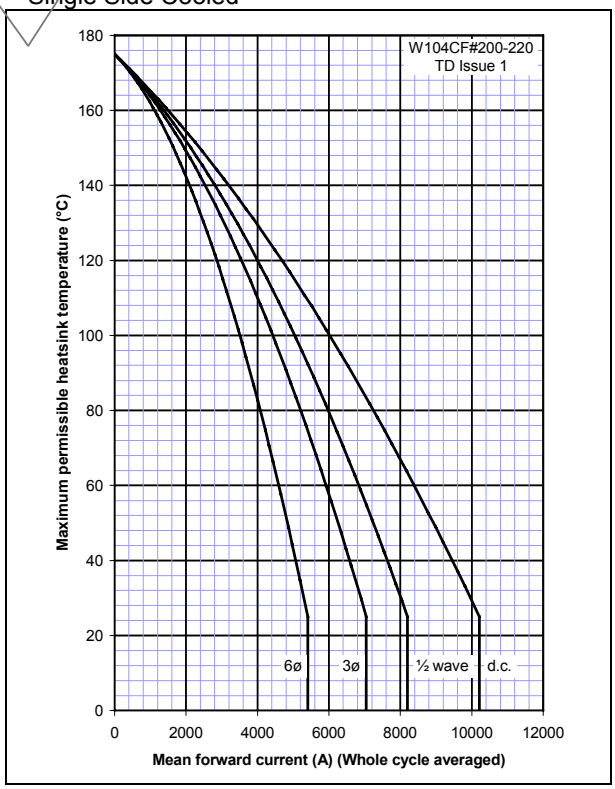
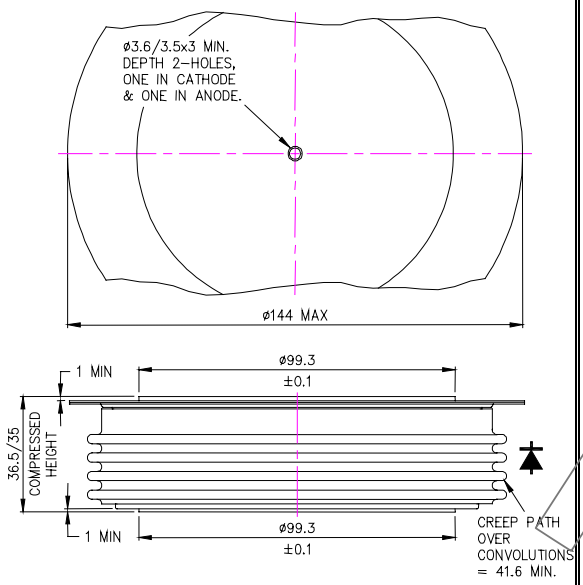


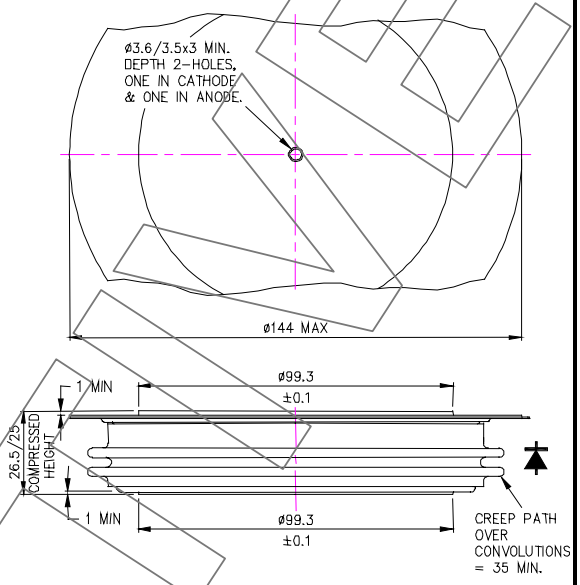
Figure 11 – Forward current vs. Heatsink temperature – Single Side Cooled



Outline Drawing & Ordering Information



FC = Standard capsule



FD = Standard capsule

ORDERING INFORMATION (Please quote 10 digit code as below)

W104C	F#	♦♦	0
Fixed Type Code	Outline Code FC = Standard 36mm capsule FD = Standard 26mm capsule	Voltage code V_{RRM}/100 20-22	Fixed code

Typical order code: W104CFC220 – 2200V V_{RRM}, 36mm clamp height standard capsule.

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